## NSN 5961-00-463-3014

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View Online at https://aerobasegroup.com/nsn/5961-00-463-3014 **Inclosure Material:** Metal **Overall Length:** 0.360 inches **Overall Diameter:** 1.220 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-36 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 60.0 emitter to base voltage, static, collector open and 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current blank and 4.00 amperes source cutoff current **Transfer Ratio:** 80.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 uninsulated wire lead Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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